



钜地半导体
Tudi Semiconductor

Product Specification

TUDI-LD1117

Adjustable and fixed low drop positive voltage regulator

网址 www.sztdbdt.com 🔍

用芯智造 · 卓越品质

**semiconductor device
manufacturer**

- Design
- research and development
- production
- and sales



Features

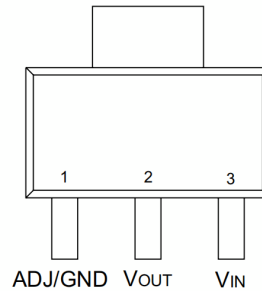
- Low dropout voltage (1 V typ.)
- 2.85 V device performances are suitable for SCSI-2 active termination
- Output current up to 800 mA
- Fixed output voltage of: 1.2 V, 1.8 V, 2.5 V, 3.3 V, 5.0 V
- Adjustable version availability ($V_{REF} = 1.25$ V)
- Internal current and thermal limit
- Available in ± 1 % (at 25 °C) and 2 % in full temperature range
- Supply voltage rejection: 75 dB (typ.)

Description

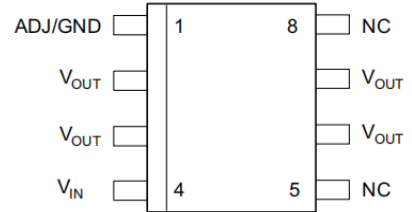
The LD1117 is a low drop voltage regulator able to provide up to 800 mA of output current, available even in adjustable version ($V_{REF} = 1.25$ V). Concerning fixed versions, are offered the following output voltages: 1.2 V, 1.8 V, 2.5 V, 2.85 V, 3.3 V and 5.0 V. The device is supplied in: SOT-223, DPAK, SO-8 and TO-220.

The SOT-223 and DPAK surface mount packages optimize the thermal characteristics even offering a relevant space saving effect. High efficiency is assured by NPN pass transistor. In fact in this case, unlike than PNP one, the quiescent current flows mostly into the load. Only a very common 10 μ F minimum capacitor is needed for stability. On chip trimming allows the regulator to reach a very tight output voltage tolerance, within ± 1 % at 25 °C. The adjustable LD1117 is pin to pin compatible with the other standard. Adjustable voltage regulators maintaining the better performances in terms of drop and tolerance.

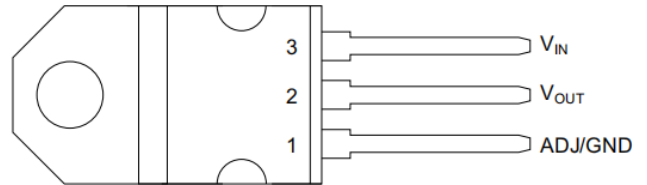
SOT-223



SOP-8



TO-220

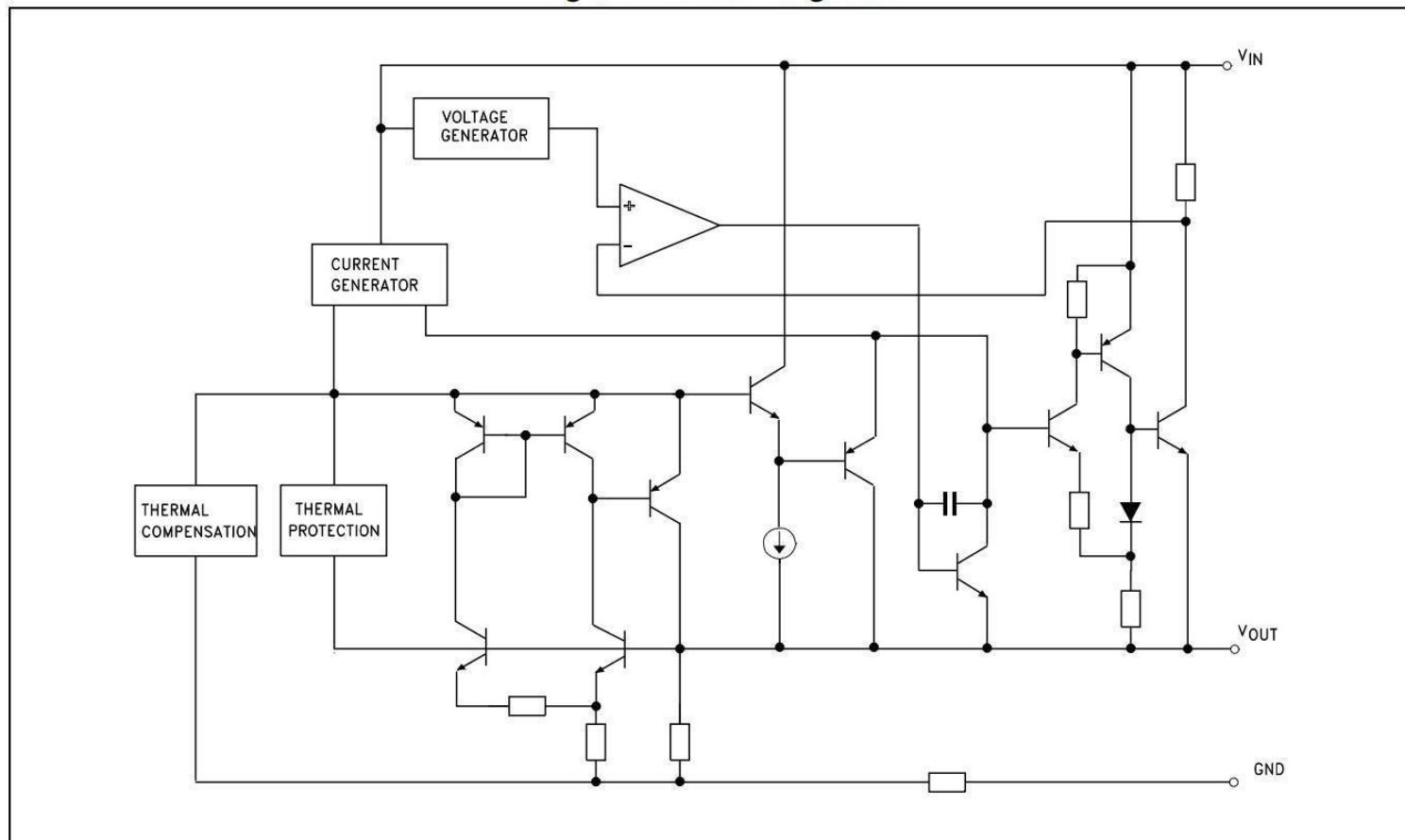




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Diagram

Figure 1. Block diagram





3 Maximum ratings

Table 1. Absolute maximum ratings

Symbol	Parameter		Value	Unit
$V_{IN}^{(1)}$	DC input voltage		15	V
P_{TOT}	Power dissipation		12	W
T_{STG}	Storage temperature range		-40 to +150	°C
T_{OP}	Operating junction temperature range	for C version	-40 to +125	°C
		for standard version	0 to +125	°C

1. Absolute maximum rating of $V_{IN} = 18$ V, when I_{OUT} is lower than 20 mA.

Table 2. Thermal data

Symbol	Parameter	SOT-223	SO-8	DPAK	TO-220	Unit
R_{thJC}	Thermal resistance junction-case	15	20	8	5	°C/W
R_{thJA}	Thermal resistance junction-ambient	110	55	100	50	°C/W



4 Schematic application

Figure 3. Application circuit (for 1.2 V)

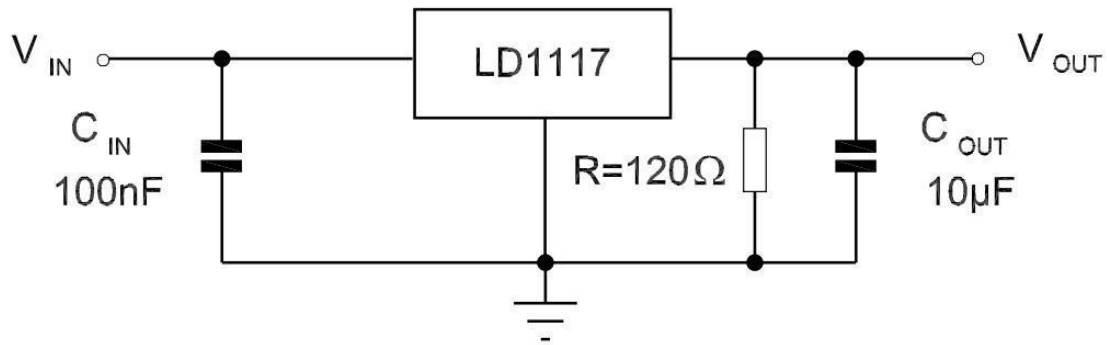
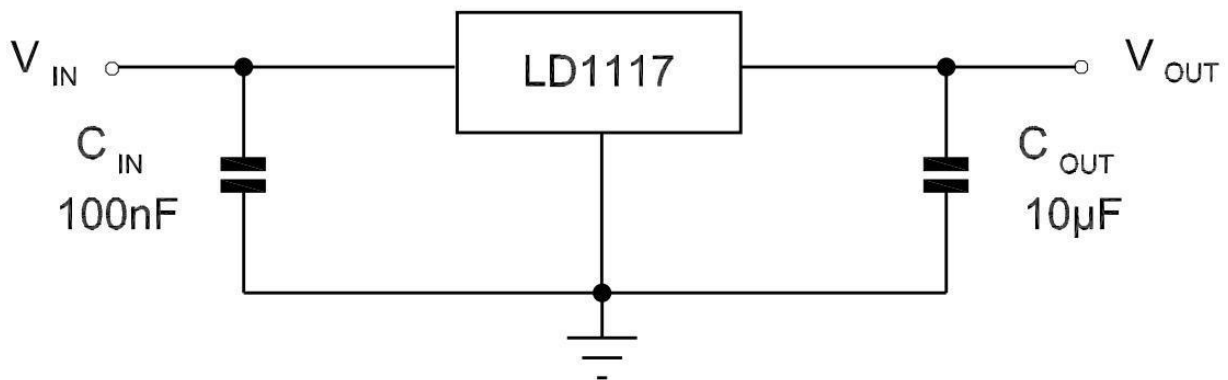


Figure 4. Application circuit (for other fixed output voltages)





5 Electrical characteristics

Refer to the test circuits, $T_J = 0$ to $125\text{ }^{\circ}\text{C}$, $C_O = 10\text{ }\mu\text{F}$, $R = 120\text{ }\Omega$ between GND and OUT pins, unless otherwise specified.

Table 3. Electrical characteristics of LD1117#12

Symbol	Parameter	Test condition	Min.	Typ.	Max.	Unit
V_O	Output voltage	$V_{in} = 3.2\text{ V}$, $I_O = 10\text{ mA}$, $T_J = 25\text{ }^{\circ}\text{C}$	1.188	1.20	1.212	V
V_O	Output voltage	$I_O = 10$ to 800 mA $V_{in} - V_O = 1.4$ to 10 V	1.140	1.20	1.260	V
ΔV_O	Line regulation	$V_{in} - V_O = 1.5$ to 13.75 V , $I_O = 10\text{ mA}$		0.035	0.2	%
ΔV_O	Load regulation	$V_{in} - V_O = 3\text{ V}$, $I_O = 10$ to 800 mA		0.1	0.4	%
ΔV_O	Temperature stability			0.5		%
ΔV_O	Long term stability	1000 hrs, $T_J = 125\text{ }^{\circ}\text{C}$		0.3		%
V_{in}	Operating input voltage				15	V
I_{adj}	Adjustment pin current	$V_{in} \leq 15\text{ V}$		60	120	μA
ΔI_{adj}	Adjustment pin current change	$V_{in} - V_O = 1.4$ to 10 V $I_O = 10$ to 800 mA		1	5	μA
$I_{O(min)}$	Minimum load current	$V_{in} = 15\text{ V}$		2	5	mA
I_O	Output current	$V_{in} - V_O = 5\text{ V}$, $T_J = 25\text{ }^{\circ}\text{C}$	800	950	1300	mA
eN	Output noise (% V_O)	$B = 10\text{ Hz}$ to 10 kHz , $T_J = 25\text{ }^{\circ}\text{C}$		0.003		%
SVR	Supply voltage rejection	$I_O = 40\text{ mA}$, $f = 120\text{ Hz}$, $T_J = 25\text{ }^{\circ}\text{C}$ $V_{in} - V_O = 3\text{ V}$, $V_{ripple} = 1\text{ V}_{PP}$	60	75		dB
V_d	Dropout voltage	$I_O = 100\text{ mA}$		1	1.1	V
		$I_O = 500\text{ mA}$		1.05	1.15	
		$I_O = 800\text{ mA}$		1.10	1.2	
	Thermal regulation	$T_a = 25\text{ }^{\circ}\text{C}$, 30 ms Pulse		0.01	0.1	%/W



Refer to the test circuits, $T_J = 0$ to $125\text{ }^{\circ}\text{C}$, $C_O = 10\text{ }\mu\text{F}$, unless otherwise specified.

Table 4. Electrical characteristics of LD1117#18

Symbol	Parameter	Test condition	Min.	Typ.	Max.	Unit
V_O	Output voltage	$V_{in} = 3.8\text{ V}$, $I_O = 10\text{ mA}$, $T_J = 25\text{ }^{\circ}\text{C}$	1.78	1.8	1.82	V
V_O	Output voltage	$I_O = 0$ to 800 mA , $V_{in} = 3.3$ to 8 V	1.76		1.84	V
ΔV_O	Line regulation	$V_{in} = 3.3$ to 8 V , $I_O = 0\text{ mA}$		1	6	mV
ΔV_O	Load regulation	$V_{in} = 3.3\text{ V}$, $I_O = 0$ to 800 mA		1	10	mV
ΔV_O	Temperature stability			0.5		%
ΔV_O	Long term stability	1000 hrs, $T_J = 125\text{ }^{\circ}\text{C}$		0.3		%
V_{in}	Operating input voltage	$I_O = 100\text{ mA}$			15	V
I_d	Quiescent current	$V_{in} \leq 8\text{ V}$		5	10	mA
I_O	Output current	$V_{in} = 6.8\text{ V}$, $T_J = 25\text{ }^{\circ}\text{C}$	800	950	1300	mA
eN	Output noise voltage	$B = 10\text{ Hz}$ to 10 kHz , $T_J = 25\text{ }^{\circ}\text{C}$		100		μV
SVR	Supply voltage rejection	$I_O = 40\text{ mA}$, $f = 120\text{ Hz}$, $T_J = 25\text{ }^{\circ}\text{C}$ $V_{in} = 5.5\text{ V}$, $V_{ripple} = 1\text{ V}_{PP}$	60	75		dB
V_d	Dropout voltage	$I_O = 100\text{ mA}$		1	1.1	V
		$I_O = 500\text{ mA}$		1.05	1.15	
		$I_O = 800\text{ mA}$		1.10	1.2	
	Thermal regulation	$T_a = 25\text{ }^{\circ}\text{C}$, 30 ms Pulse		0.01	0.1	%/W



Refer to the test circuits, $T_J = 0$ to $125\text{ }^{\circ}\text{C}$, $C_O = 10\text{ }\mu\text{F}$, unless otherwise specified.

Table 5. Electrical characteristics of LD1117#25

Symbol	Parameter	Test condition	Min.	Typ.	Max.	Unit
V_O	Output voltage	$V_{in} = 4.5\text{ V}$, $I_O = 10\text{ mA}$, $T_J = 25\text{ }^{\circ}\text{C}$	2.475	2.5	2.525	V
V_O	Output voltage	$I_O = 0$ to 800 mA , $V_{in} = 3.9$ to 10 V	2.45		2.55	V
ΔV_O	Line regulation	$V_{in} = 3.9$ to 10 V , $I_O = 0\text{ mA}$		1	6	mV
ΔV_O	Load regulation	$V_{in} = 3.9\text{ V}$, $I_O = 0$ to 800 mA		1	10	mV
ΔV_O	Temperature stability			0.5		%
ΔV_O	Long term stability	1000 hrs, $T_J = 125\text{ }^{\circ}\text{C}$		0.3		%
V_{in}	Operating input voltage	$I_O = 100\text{ mA}$			15	V
I_d	Quiescent current	$V_{in} \leq 10\text{ V}$		5	10	mA
I_O	Output current	$V_{in} = 7.5\text{ V}$, $T_J = 25\text{ }^{\circ}\text{C}$	800	950	1300	mA
eN	Output noise voltage	$B = 10\text{ Hz}$ to 10 kHz , $T_J = 25\text{ }^{\circ}\text{C}$		100		μV
SVR	Supply voltage rejection	$I_O = 40\text{ mA}$, $f = 120\text{ Hz}$, $T_J = 25\text{ }^{\circ}\text{C}$ $V_{in} = 5.5\text{ V}$, $V_{ripple} = 1\text{ V}_{PP}$	60	75		dB
V_d	Dropout voltage	$I_O = 100\text{ mA}$		1	1.1	V
		$I_O = 500\text{ mA}$		1.05	1.15	
		$I_O = 800\text{ mA}$		1.10	1.2	
	Thermal regulation	$T_a = 25\text{ }^{\circ}\text{C}$, 30 ms Pulse		0.01	0.1	%/W



Refer to the test circuits, $T_J = 0$ to $125\text{ }^{\circ}\text{C}$, $C_O = 10\text{ }\mu\text{F}$, unless otherwise specified.

Table 6. Electrical characteristics of LD1117#33

Symbol	Parameter	Test condition	Min.	Typ.	Max.	Unit
V_O	Output voltage	$V_{in} = 5.3\text{ V}$, $I_O = 10\text{ mA}$, $T_J = 25\text{ }^{\circ}\text{C}$	3.267	3.3	3.333	V
V_O	Output voltage	$I_O = 0$ to 800 mA , $V_{in} = 4.75$ to 10 V	3.235		3.365	V
ΔV_O	Line regulation	$V_{in} = 4.75$ to 15 V , $I_O = 0\text{ mA}$		1	6	mV
ΔV_O	Load regulation	$V_{in} = 4.75\text{ V}$, $I_O = 0$ to 800 mA		1	10	mV
ΔV_O	Temperature stability			0.5		%
ΔV_O	Long term stability	1000 hrs, $T_J = 125\text{ }^{\circ}\text{C}$		0.3		%
V_{in}	Operating input voltage	$I_O = 100\text{ mA}$			15	V
I_d	Quiescent current	$V_{in} \leq 15\text{ V}$		5	10	mA
I_O	Output current	$V_{in} = 8.3\text{ V}$, $T_J = 25\text{ }^{\circ}\text{C}$	800	950	1300	mA
eN	Output noise voltage	$B = 10\text{ Hz}$ to 10 kHz , $T_J = 25\text{ }^{\circ}\text{C}$		100		μV
SVR	Supply voltage rejection	$I_O = 40\text{ mA}$, $f = 120\text{ Hz}$, $T_J = 25\text{ }^{\circ}\text{C}$ $V_{in} = 6.3\text{ V}$, $V_{ripple} = 1\text{ V}_{PP}$	60	75		dB
V_d	Dropout voltage	$I_O = 100\text{ mA}$		1	1.1	V
		$I_O = 500\text{ mA}$		1.05	1.15	
		$I_O = 800\text{ mA}$		1.10	1.2	
	Thermal regulation	$T_a = 25\text{ }^{\circ}\text{C}$, 30 ms Pulse		0.01	0.1	%/W



Refer to the test circuits, $T_J = 0$ to $125\text{ }^{\circ}\text{C}$, $C_O = 10\text{ }\mu\text{F}$, unless otherwise specified.

Table 7. Electrical characteristics of LD1117#50

Symbol	Parameter	Test condition	Min.	Typ.	Max.	Unit
V_O	Output voltage	$V_{in} = 7\text{ V}$, $I_O = 10\text{ mA}$, $T_J = 25\text{ }^{\circ}\text{C}$	4.95	5	5.05	V
V_O	Output voltage	$I_O = 0$ to 800 mA , $V_{in} = 6.5$ to 15 V	4.9		5.1	V
ΔV_O	Line regulation	$V_{in} = 6.5$ to 15 V , $I_O = 0\text{ mA}$		1	10	mV
ΔV_O	Load regulation	$V_{in} = 6.5\text{ V}$, $I_O = 0$ to 800 mA		1	15	mV
ΔV_O	Temperature stability			0.5		%
ΔV_O	Long term stability	1000 hrs, $T_J = 125\text{ }^{\circ}\text{C}$		0.3		%
V_{in}	Operating input voltage	$I_O = 100\text{ mA}$			15	V
I_d	Quiescent current	$V_{in} \leq 15\text{ V}$		5	10	mA
I_O	Output current	$V_{in} = 10\text{ V}$, $T_J = 25\text{ }^{\circ}\text{C}$	800	950	1300	mA
eN	Output noise voltage	$B = 10\text{ Hz}$ to 10 kHz , $T_J = 25\text{ }^{\circ}\text{C}$		100		μV
SVR	Supply voltage rejection	$I_O = 40\text{ mA}$, $f = 120\text{ Hz}$, $T_J = 25\text{ }^{\circ}\text{C}$ $V_{in} = 8\text{ V}$, $V_{ripple} = 1\text{ V}_{PP}$	60	75		dB
V_d	Dropout voltage	$I_O = 100\text{ mA}$		1	1.1	V
		$I_O = 500\text{ mA}$		1.05	1.15	
		$I_O = 800\text{ mA}$		1.10	1.2	
	Thermal regulation	$T_a = 25\text{ }^{\circ}\text{C}$, 30 ms Pulse		0.01	0.1	%/W



Refer to the test circuits, $T_J = 0$ to $125\text{ }^{\circ}\text{C}$, $C_O = 10\text{ }\mu\text{F}$, unless otherwise specified.

Table 8. Electrical characteristics of LD1117 (adjustable)

Symbol	Parameter	Test condition	Min.	Typ.	Max.	Unit
V_{ref}	Reference voltage	$V_{\text{in}} - V_O = 2\text{ V}$, $I_O = 10\text{ mA}$, $T_J = 25\text{ }^{\circ}\text{C}$	1.238	1.25	1.262	V
V_{ref}	Reference voltage	$I_O = 10$ to 800 mA , $V_{\text{in}} - V_O = 1.4$ to 10 V	1.225		1.275	V
ΔV_O	Line regulation	$V_{\text{in}} - V_O = 1.5$ to 13.75 V , $I_O = 10\text{ mA}$		0.035	0.2	%
ΔV_O	Load regulation	$V_{\text{in}} - V_O = 3\text{ V}$, $I_O = 10$ to 800 mA		0.1	0.4	%
ΔV_O	Temperature stability			0.5		%
ΔV_O	Long term stability	1000 hrs, $T_J = 125\text{ }^{\circ}\text{C}$		0.3		%
V_{in}	Operating input voltage				15	V
I_{adj}	Adjustment pin current	$V_{\text{in}} \leq 15\text{ V}$		60	120	μA
ΔI_{adj}	Adjustment pin current change	$V_{\text{in}} - V_O = 1.4$ to 10 V , $I_O = 10$ to 800 mA		1	5	μA
$I_{O(\text{min})}$	Minimum load current	$V_{\text{in}} = 15\text{ V}$		2	5	mA
I_O	Output current	$V_{\text{in}} - V_O = 5\text{ V}$, $T_J = 25\text{ }^{\circ}\text{C}$	800	950	1300	mA
eN	Output noise (% V_O)	$B = 10\text{ Hz}$ to 10 kHz , $T_J = 25\text{ }^{\circ}\text{C}$		0.003		%
SVR	Supply voltage rejection	$I_O = 40\text{ mA}$, $f = 120\text{ Hz}$, $T_J = 25\text{ }^{\circ}\text{C}$ $V_{\text{in}} - V_O = 3\text{ V}$, $V_{\text{ripple}} = 1\text{ V}_{\text{PP}}$	60	75		dB
V_d	Dropout voltage	$I_O = 100\text{ mA}$		1	1.1	V
		$I_O = 500\text{ mA}$		1.05	1.15	
		$I_O = 800\text{ mA}$		1.10	1.2	
	Thermal regulation	$T_a = 25\text{ }^{\circ}\text{C}$, 30 ms Pulse		0.01	0.1	%/W



Refer to the test circuits, $T_J = -40$ to $125\text{ }^{\circ}\text{C}$, $C_O = 10\text{ }\mu\text{F}$, $R = 120\text{ }\Omega$ between GND and OUT pins, unless otherwise specified.

Table 9. Electrical characteristics of LD1117#12C

Symbol	Parameter	Test condition	Min.	Typ.	Max.	Unit
V_O	Output voltage	$V_{in} - V_O = 2\text{ V}$, $I_O = 10\text{ mA}$, $T_J = 25\text{ }^{\circ}\text{C}$	1.176	1.20	1.224	V
V_O	Output voltage	$I_O = 10$ to 800 mA , $V_{in} - V_O = 1.4$ to 10 V	1.120	1.20	1.280	V
ΔV_O	Line regulation	$V_{in} - V_O = 1.5$ to 13.75 V , $I_O = 10\text{ mA}$			1	%
ΔV_O	Load regulation	$V_{in} - V_O = 3\text{ V}$, $I_O = 10$ to 800 mA			1	%
ΔV_O	Temperature stability			0.5		%
ΔV_O	Long term stability	1000 hrs, $T_J = 125\text{ }^{\circ}\text{C}$		0.3		%
V_{in}	Operating input voltage				15	V
I_{adj}	Adjustment pin current	$V_{in} \leq 15\text{ V}$		60	120	μA
ΔI_{adj}	Adjustment pin current change	$V_{in} - V_O = 1.4$ to 10 V $I_O = 10$ to 800 mA		1	5	μA
$I_{O(min)}$	Minimum load current	$V_{in} = 15\text{ V}$		2	5	mA
I_O	Output current	$V_{in} - V_O = 5\text{ V}$, $T_J = 25\text{ }^{\circ}\text{C}$	800	950	1300	mA
eN	Output noise (% V_O)	$B = 10\text{ Hz}$ to 10 kHz , $T_J = 25\text{ }^{\circ}\text{C}$		0.003		%
SVR	Supply voltage rejection	$I_O = 40\text{ mA}$, $f = 120\text{ Hz}$, $T_J = 25\text{ }^{\circ}\text{C}$ $V_{in} - V_O = 3\text{ V}$, $V_{ripple} = 1\text{ V}_{PP}$	60	75		dB
V_d	Dropout voltage	$I_O = 100\text{ mA}$, $T_J = 0$ to $125\text{ }^{\circ}\text{C}$		1	1.1	V
		$I_O = 500\text{ mA}$, $T_J = 0$ to $125\text{ }^{\circ}\text{C}$		1.05	1.2	
		$I_O = 800\text{ mA}$, $T_J = 0$ to $125\text{ }^{\circ}\text{C}$		1.10	1.3	
	Thermal regulation	$T_a = 25\text{ }^{\circ}\text{C}$, 30 ms Pulse		0.01	0.1	%/W



Refer to the test circuits, $T_J = -40$ to $125\text{ }^{\circ}\text{C}$, $C_O = 10\text{ }\mu\text{F}$, unless otherwise specified.

Table 10. Electrical characteristics of LD1117#18C

Symbol	Parameter	Test condition	Min.	Typ.	Max.	Unit
V_O	Output voltage	$V_{in} = 3.8\text{ V}$, $I_O = 10\text{ mA}$, $T_J = 25\text{ }^{\circ}\text{C}$	1.76	1.8	1.84	V
V_O	Output voltage	$I_O = 0$ to 800 mA , $V_{in} = 3.9$ to 10 V	1.73		1.87	V
ΔV_O	Line regulation	$V_{in} = 3.3$ to 8 V , $I_O = 0\text{ mA}$		1	30	mV
ΔV_O	Load regulation	$V_{in} = 3.3\text{ V}$, $I_O = 0$ to 800 mA		1	30	mV
ΔV_O	Temperature stability			0.5		%
ΔV_O	Long term stability	1000 hrs, $T_J = 125\text{ }^{\circ}\text{C}$		0.3		%
V_{in}	Operating input voltage	$I_O = 100\text{ mA}$			15	V
I_d	Quiescent current	$V_{in} \leq 8\text{ V}$		5	10	mA
I_O	Output current	$V_{in} = 6.8\text{ V}$, $T_J = 25\text{ }^{\circ}\text{C}$	800	950	1300	mA
eN	Output noise voltage	$B = 10\text{ Hz}$ to 10 kHz , $T_J = 25\text{ }^{\circ}\text{C}$		100		μV
SVR	Supply voltage rejection	$I_O = 40\text{ mA}$, $f = 120\text{ Hz}$, $T_J = 25\text{ }^{\circ}\text{C}$ $V_{in} = 5.5\text{ V}$, $V_{ripple} = 1\text{ V}_{PP}$	60	75		dB
V_d	Dropout voltage	$I_O = 100\text{ mA}$, $T_J = 0$ to $125\text{ }^{\circ}\text{C}$		1	1.1	V
		$I_O = 500\text{ mA}$, $T_J = 0$ to $125\text{ }^{\circ}\text{C}$		1.05	1.15	
		$I_O = 800\text{ mA}$, $T_J = 0$ to $125\text{ }^{\circ}\text{C}$		1.10	1.2	
V_d	Dropout voltage	$I_O = 100\text{ mA}$			1.1	V
		$I_O = 500\text{ mA}$			1.2	
		$I_O = 800\text{ mA}$			1.3	
	Thermal regulation	$T_a = 25\text{ }^{\circ}\text{C}$, 30 ms Pulse		0.01	0.1	%/W



Refer to the test circuits, $T_J = -40$ to $125\text{ }^{\circ}\text{C}$, $C_O = 10\text{ }\mu\text{F}$, unless otherwise specified.

Table 11. Electrical characteristics of LD1117#25C

Symbol	Parameter	Test condition	Min.	Typ.	Max.	Unit
V_O	Output voltage	$V_{in} = 4.5\text{ V}$, $I_O = 10\text{ mA}$, $T_J = 25\text{ }^{\circ}\text{C}$	2.45	2.5	2.55	V
V_O	Output voltage	$I_O = 0$ to 800 mA , $V_{in} = 3.9$ to 10 V	2.4		2.6	V
ΔV_O	Line regulation	$V_{in} = 3.9$ to 10 V , $I_O = 0\text{ mA}$		1	30	mV
ΔV_O	Load regulation	$V_{in} = 3.9\text{ V}$, $I_O = 0$ to 800 mA		1	30	mV
ΔV_O	Temperature stability			0.5		%
ΔV_O	Long term stability	1000 hrs, $T_J = 125\text{ }^{\circ}\text{C}$		0.3		%
V_{in}	Operating input voltage	$I_O = 100\text{ mA}$			15	V
I_d	Quiescent current	$V_{in} \leq 10\text{ V}$		5	10	mA
I_O	Output current	$V_{in} = 7.5\text{ V}$, $T_J = 25\text{ }^{\circ}\text{C}$	800	950	1300	mA
eN	Output noise voltage	$B = 10\text{ Hz}$ to 10 kHz , $T_J = 25\text{ }^{\circ}\text{C}$		100		μV
SVR	Supply voltage rejection	$I_O = 40\text{ mA}$, $f = 120\text{ Hz}$, $T_J = 25\text{ }^{\circ}\text{C}$ $V_{in} = 5.5\text{ V}$, $V_{ripple} = 1\text{ V}_{PP}$	60	75		dB
V_d	Dropout voltage	$I_O = 100\text{ mA}$, $T_J = 0$ to $125\text{ }^{\circ}\text{C}$		1	1.1	V
		$I_O = 500\text{ mA}$, $T_J = 0$ to $125\text{ }^{\circ}\text{C}$		1.05	1.15	
		$I_O = 800\text{ mA}$, $T_J = 0$ to $125\text{ }^{\circ}\text{C}$		1.10	1.2	
V_d	Dropout voltage	$I_O = 100\text{ mA}$			1.1	V
		$I_O = 500\text{ mA}$			1.2	
		$I_O = 800\text{ mA}$			1.3	
	Thermal regulation	$T_a = 25\text{ }^{\circ}\text{C}$, 30 ms Pulse		0.01	0.1	%/W



Refer to the test circuits, $T_J = -40$ to $125\text{ }^{\circ}\text{C}$, $C_O = 10\text{ }\mu\text{F}$, unless otherwise specified.

Table 12. Electrical characteristics of LD1117#33C

Symbol	Parameter	Test condition	Min.	Typ.	Max.	Unit
V_O	Output voltage	$V_{in} = 5.3\text{ V}$, $I_O = 10\text{ mA}$, $T_J = 25\text{ }^{\circ}\text{C}$	3.24	3.3	3.36	V
V_O	Output voltage	$I_O = 0$ to 800 mA , $V_{in} = 4.75$ to 10 V	3.16		3.44	V
ΔV_O	Line regulation	$V_{in} = 4.75$ to 15 V , $I_O = 0\text{ mA}$		1	30	mV
ΔV_O	Load regulation	$V_{in} = 4.75\text{ V}$, $I_O = 0$ to 800 mA		1	30	mV
ΔV_O	Temperature stability			0.5		%
ΔV_O	Long term stability	1000 hrs, $T_J = 125\text{ }^{\circ}\text{C}$		0.3		%
V_{in}	Operating input voltage	$I_O = 100\text{ mA}$			15	V
I_d	Quiescent current	$V_{in} \leq 15\text{ V}$		5	10	mA
I_O	Output current	$V_{in} = 8.3\text{ V}$, $T_J = 25\text{ }^{\circ}\text{C}$	800	950	1300	mA
eN	Output noise voltage	$B = 10\text{ Hz}$ to 10 kHz , $T_J = 25\text{ }^{\circ}\text{C}$		100		μV
SVR	Supply voltage rejection	$I_O = 40\text{ mA}$, $f = 120\text{ Hz}$, $T_J = 25\text{ }^{\circ}\text{C}$ $V_{in} = 6.3\text{ V}$, $V_{ripple} = 1\text{ V}_{PP}$	60	75		dB
V_d	Dropout voltage	$I_O = 100\text{ mA}$, $T_J = 0$ to $125\text{ }^{\circ}\text{C}$		1	1.1	V
		$I_O = 500\text{ mA}$, $T_J = 0$ to $125\text{ }^{\circ}\text{C}$		1.05	1.15	
		$I_O = 800\text{ mA}$, $T_J = 0$ to $125\text{ }^{\circ}\text{C}$		1.10	1.2	
V_d	Dropout voltage	$I_O = 100\text{ mA}$			1.1	V
		$I_O = 500\text{ mA}$			1.2	
		$I_O = 800\text{ mA}$			1.3	
	Thermal regulation	$T_a = 25\text{ }^{\circ}\text{C}$, 30 ms Pulse		0.01	0.1	%/W



Refer to the test circuits, $T_J = -40$ to $125\text{ }^{\circ}\text{C}$, $C_O = 10\text{ }\mu\text{F}$, unless otherwise specified.

Table 13. Electrical characteristics of LD1117#50C

Symbol	Parameter	Test condition	Min.	Typ.	Max.	Unit
V_O	Output voltage	$V_{in} = 7\text{ V}$, $I_O = 10\text{ mA}$, $T_J = 25\text{ }^{\circ}\text{C}$	4.9	5	5.1	V
V_O	Output voltage	$I_O = 0$ to 800 mA , $V_{in} = 6.5$ to 15 V	4.8		5.2	V
ΔV_O	Line regulation	$V_{in} = 6.5$ to 15 V , $I_O = 0\text{ mA}$		1	50	mV
ΔV_O	Load regulation	$V_{in} = 6.5\text{ V}$, $I_O = 0$ to 800 mA		1	50	mV
ΔV_O	Temperature stability			0.5		%
ΔV_O	Long term stability	1000 hrs, $T_J = 125\text{ }^{\circ}\text{C}$		0.3		%
V_{in}	Operating input voltage	$I_O = 100\text{ mA}$			15	V
I_d	Quiescent current	$V_{in} \leq 15\text{ V}$		5	10	mA
I_O	Output current	$V_{in} = 10\text{ V}$, $T_J = 25\text{ }^{\circ}\text{C}$	800	950	1300	mA
eN	Output noise voltage	$B = 10\text{ Hz}$ to 10 kHz , $T_J = 25\text{ }^{\circ}\text{C}$		100		μV
SVR	Supply voltage rejection	$I_O = 40\text{ mA}$, $f = 120\text{ Hz}$, $T_J = 25\text{ }^{\circ}\text{C}$ $V_{in} = 8\text{ V}$, $V_{ripple} = 1\text{ V}_{PP}$	60	75		dB
V_d	Dropout voltage	$I_O = 100\text{ mA}$, $T_J = 0$ to $125\text{ }^{\circ}\text{C}$		1	1.1	V
		$I_O = 500\text{ mA}$, $T_J = 0$ to $125\text{ }^{\circ}\text{C}$		1.05	1.15	
		$I_O = 800\text{ mA}$, $T_J = 0$ to $125\text{ }^{\circ}\text{C}$		1.10	1.2	
V_d	Dropout voltage	$I_O = 100\text{ mA}$			1.1	V
		$I_O = 500\text{ mA}$			1.2	
		$I_O = 800\text{ mA}$			1.3	
	Thermal regulation	$T_a = 25\text{ }^{\circ}\text{C}$, 30 ms Pulse		0.01	0.1	%/W



Refer to the test circuits, $T_J = -40$ to $125\text{ }^{\circ}\text{C}$, $C_O = 10\text{ }\mu\text{F}$, unless otherwise specified.

Table 14. Electrical characteristics of LD1117C (adjustable)

Symbol	Parameter	Test condition	Min.	Typ.	Max.	Unit
V_{ref}	Reference voltage	$V_{\text{in}} - V_O = 2\text{ V}$, $I_O = 10\text{ mA}$, $T_J = 25\text{ }^{\circ}\text{C}$	1.225	1.25	1.275	V
V_{ref}	Reference voltage	$I_O = 10$ to 800 mA , $V_{\text{in}} - V_O = 1.4$ to 10 V	1.2		1.3	V
ΔV_O	Line regulation	$V_{\text{in}} - V_O = 1.5$ to 13.75 V , $I_O = 10\text{ mA}$			1	%
ΔV_O	Load regulation	$V_{\text{in}} - V_O = 3\text{ V}$, $I_O = 10$ to 800 mA			1	%
ΔV_O	Temperature stability			0.5		%
ΔV_O	Long term stability	1000 hrs, $T_J = 125\text{ }^{\circ}\text{C}$		0.3		%
V_{in}	Operating input voltage				15	V
I_{adj}	Adjustment pin current	$V_{\text{in}} \leq 15\text{ V}$		60	120	μA
ΔI_{adj}	Adjustment pin current change	$V_{\text{in}} - V_O = 1.4$ to 10 V , $I_O = 10$ to 800 mA		1	10	μA
$I_{O(\text{min})}$	Minimum load current	$V_{\text{in}} = 15\text{ V}$		2	5	mA
I_O	Output current	$V_{\text{in}} - V_O = 5\text{ V}$, $T_J = 25\text{ }^{\circ}\text{C}$	800	950	1300	mA
eN	Output noise (% V_O)	$B = 10\text{ Hz}$ to 10 kHz , $T_J = 25\text{ }^{\circ}\text{C}$		0.003		%
SVR	Supply voltage rejection	$I_O = 40\text{ mA}$, $f = 120\text{ Hz}$, $T_J = 25\text{ }^{\circ}\text{C}$ $V_{\text{in}} - V_O = 3\text{ V}$, $V_{\text{ripple}} = 1\text{ V}_{\text{PP}}$	60	75		dB
V_d	Dropout voltage	$I_O = 100\text{ mA}$, $T_J = 0$ to $125\text{ }^{\circ}\text{C}$		1	1.1	V
		$I_O = 500\text{ mA}$, $T_J = 0$ to $125\text{ }^{\circ}\text{C}$		1.05	1.15	
		$I_O = 800\text{ mA}$, $T_J = 0$ to $125\text{ }^{\circ}\text{C}$		1.10	1.2	
V_d	Dropout voltage	$I_O = 100\text{ mA}$			1.1	V
		$I_O = 500\text{ mA}$			1.2	
		$I_O = 800\text{ mA}$			1.3	
	Thermal regulation	$T_a = 25\text{ }^{\circ}\text{C}$, 30 ms Pulse		0.01	0.1	%/W



6 Typical application

Figure 5. Negative supply

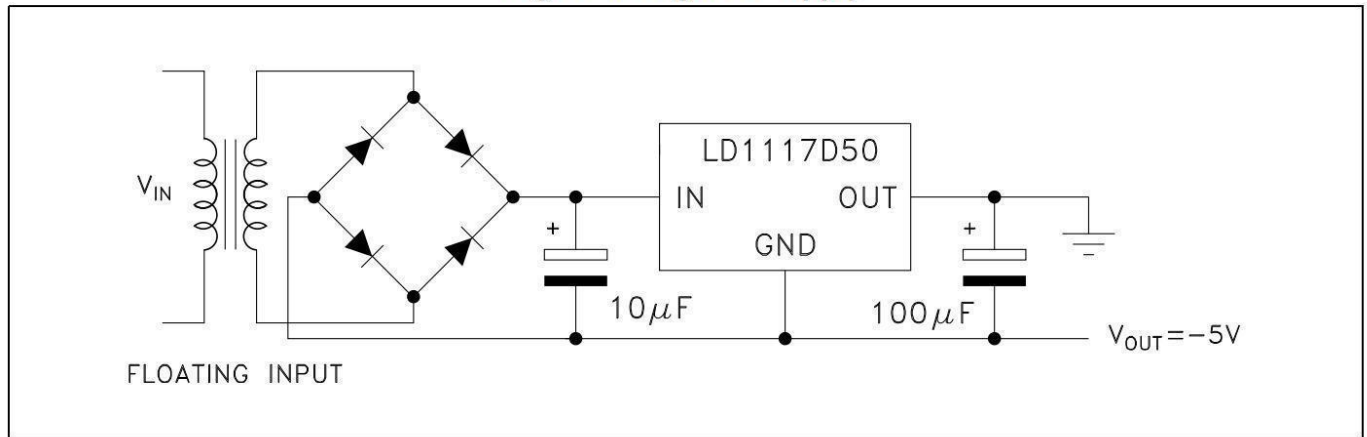


Figure 6. Circuit for increasing output voltage

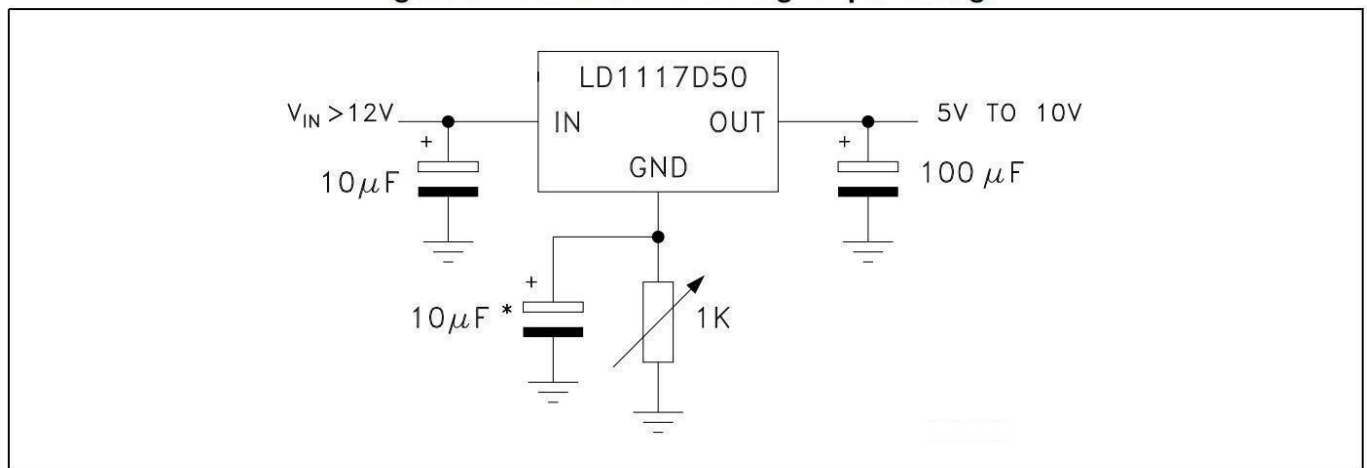


Figure 7. Voltage regulator with reference

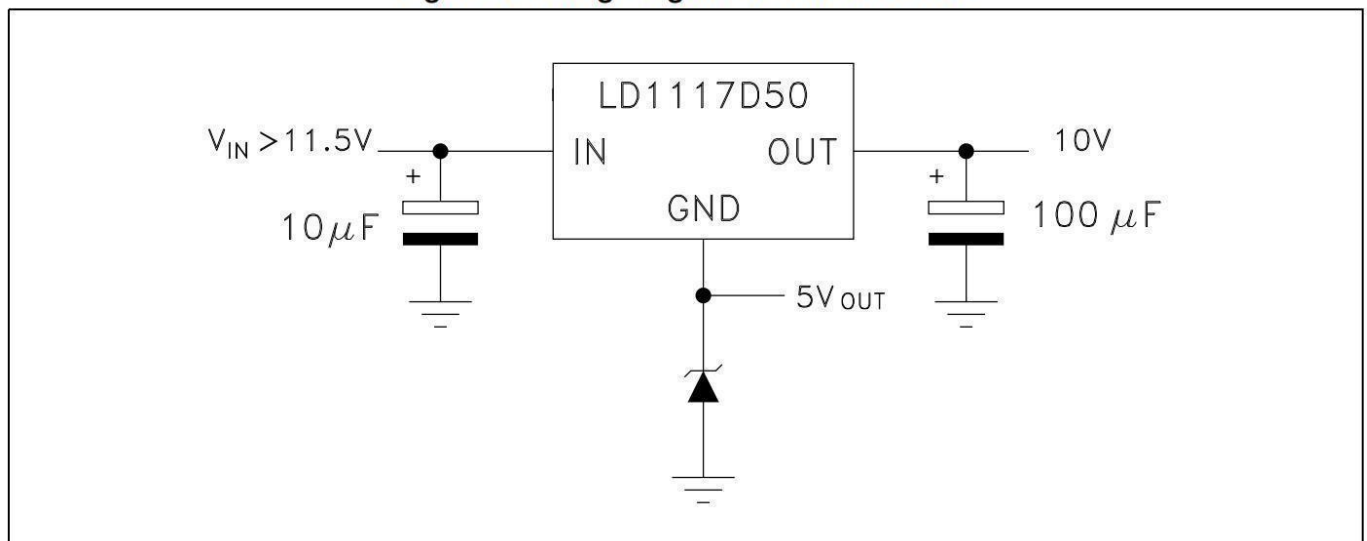




Figure 8. Battery backed-up regulated supply

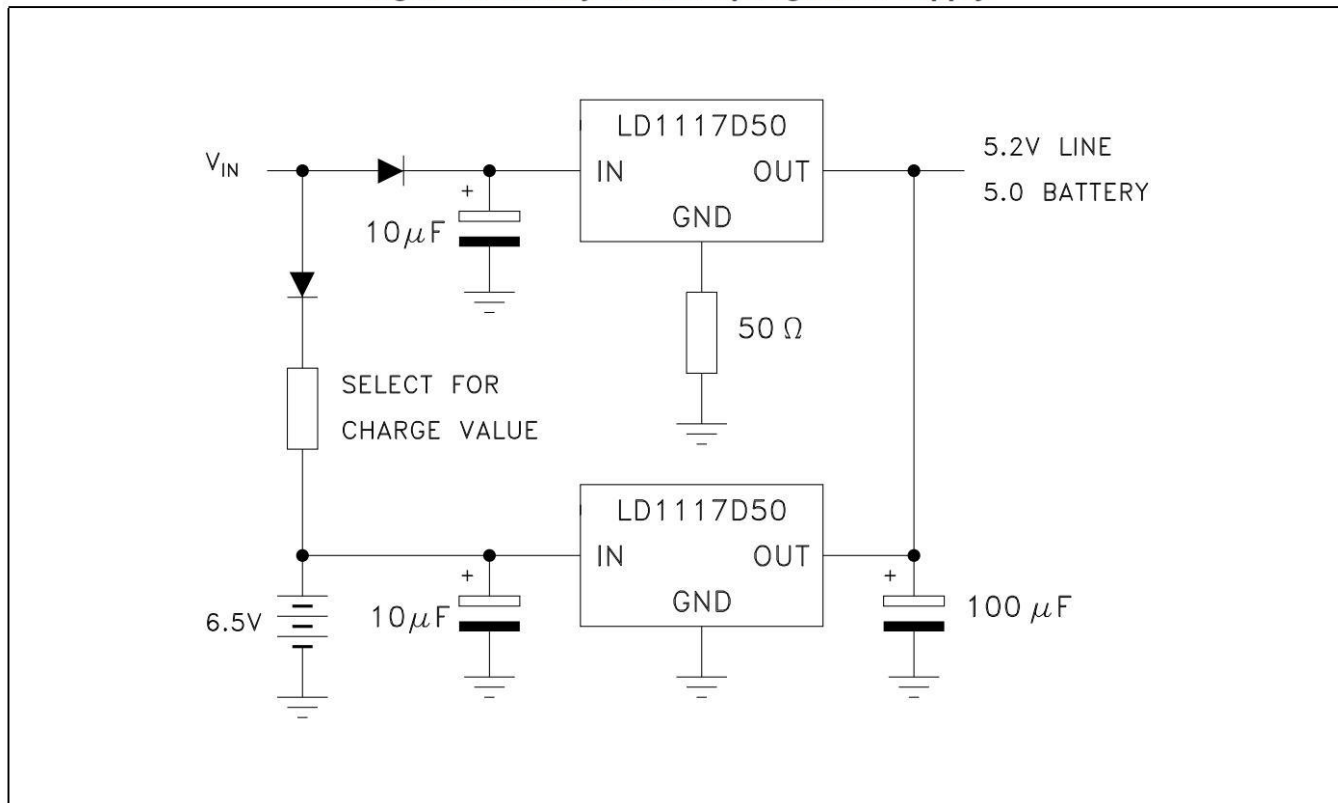
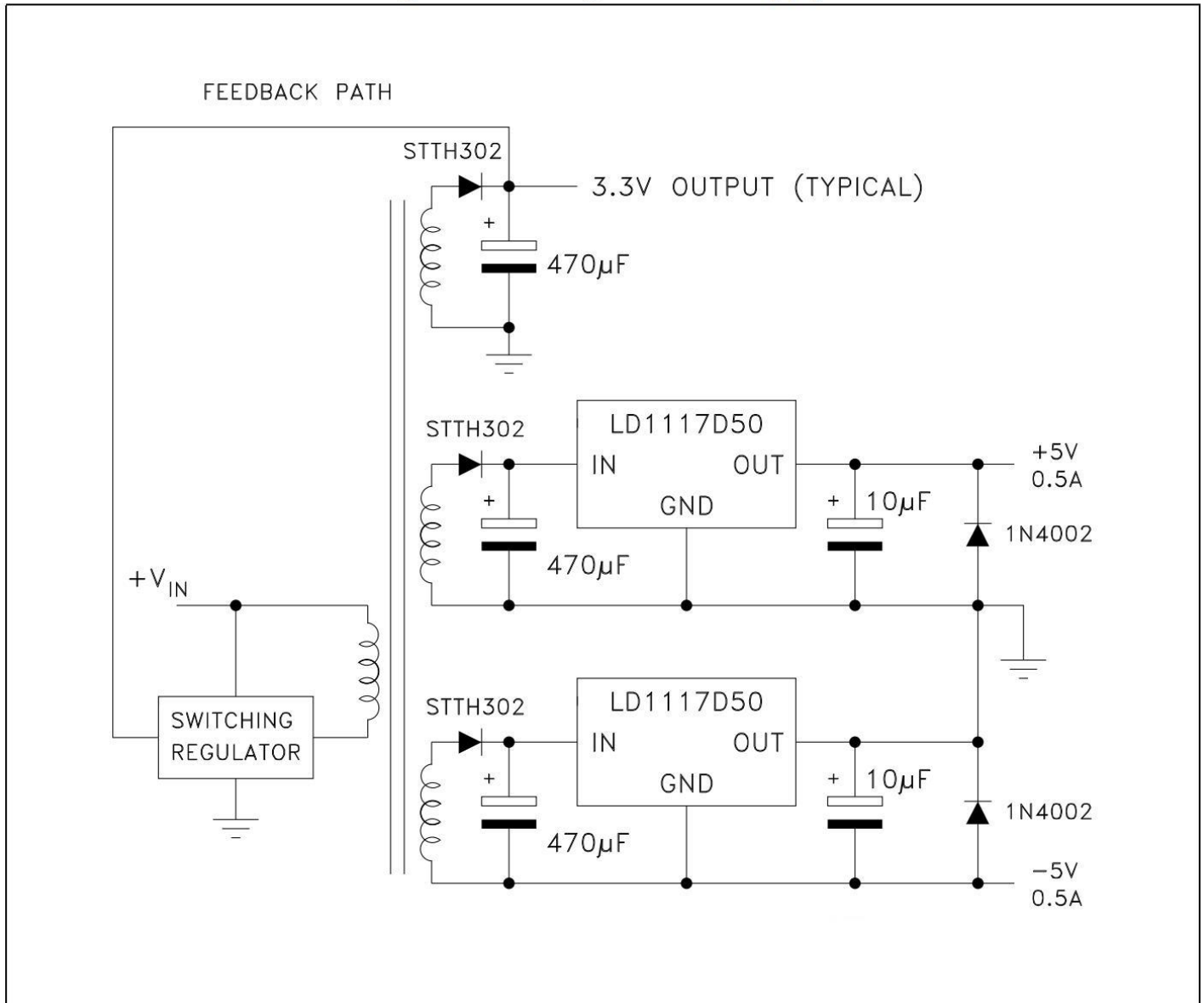




Figure 9. Post-regulated dual supply





7

LD1117 adjustable: application note

The LD1117 adjustable has a thermal stabilized 1.25 ± 0.012 V reference voltage between the OUT and ADJ pins. I_{ADJ} is 60 μ A typ. (120 μ A max.) and ΔI_{ADJ} is 1 μ A typ. (5 μ A max.).

R_1 is normally fixed to 120 Ω . From [Figure 9](#) we obtain:

$$V_{OUT} = V_{REF} + R_2 (I_{ADJ} + I_{R1}) = V_{REF} + R_2 (I_{ADJ} + V_{REF} / R_1) = V_{REF} (1 + R_2 / R_1) + R_2 \times I_{ADJ}.$$

In normal application R_2 value is in the range of few k Ω , so the $R_2 \times I_{ADJ}$ product could not be considered in the V_{OUT} calculation; then the above expression becomes:

$$V_{OUT} = V_{REF} (1 + R_2 / R_1).$$

In order to have the better load regulation it is important to realize a good Kelvin connection of R_1 and R_2 resistors. In particular R_1 connection must be realized very close to OUT and ADJ pin, while R_2 ground connection must be placed as near as possible to the negative Load pin. Ripple rejection can be improved by introducing a 10 μ F electrolytic capacitor placed in parallel to the R_2 resistor (see [Figure 10](#)).

Figure 10. Adjustable output voltage application

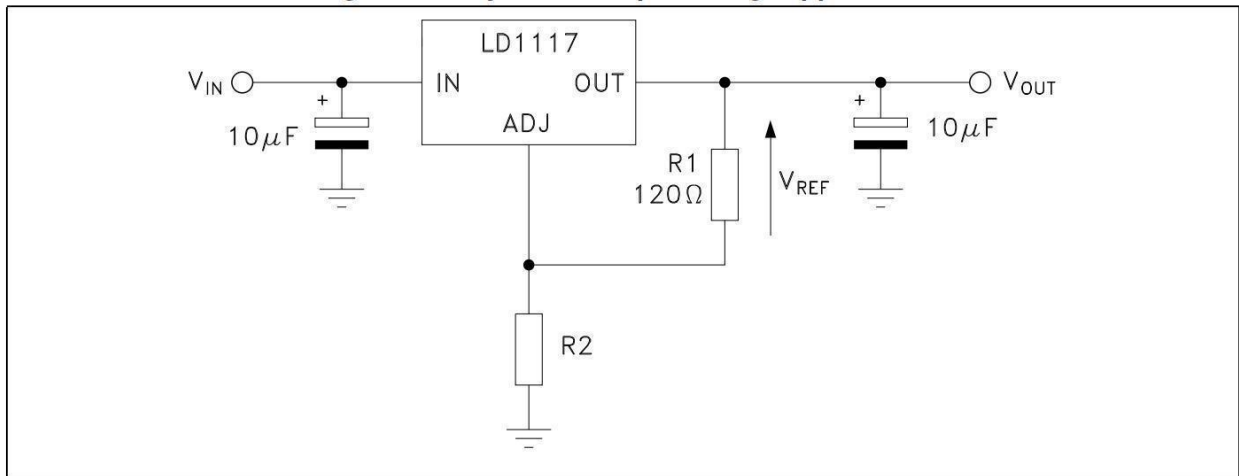
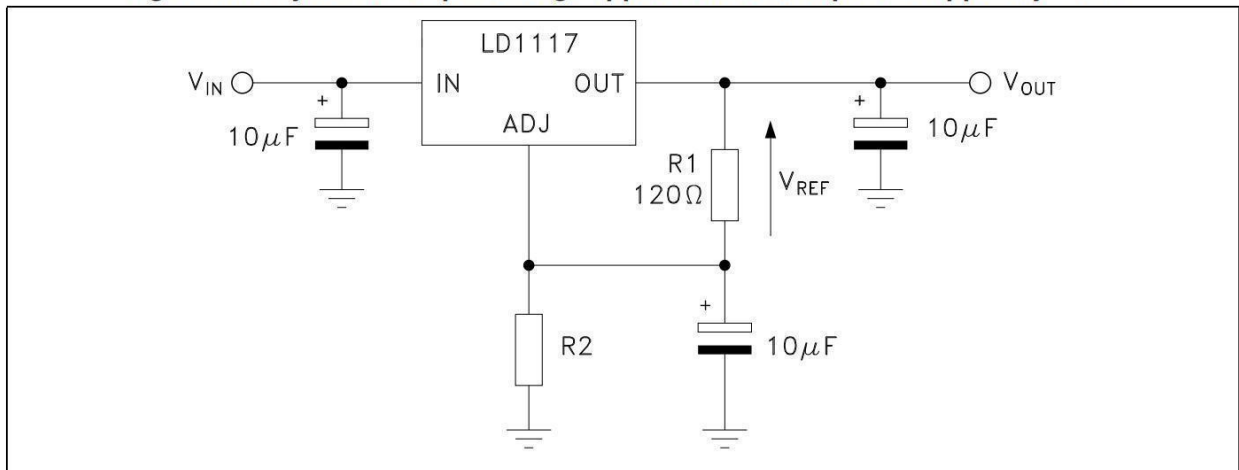


Figure 11. Adjustable output voltage application with improved ripple rejection

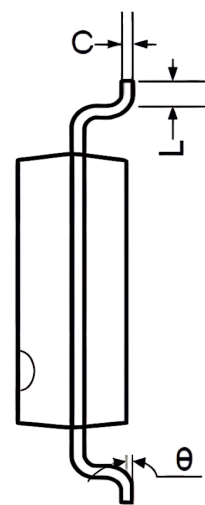
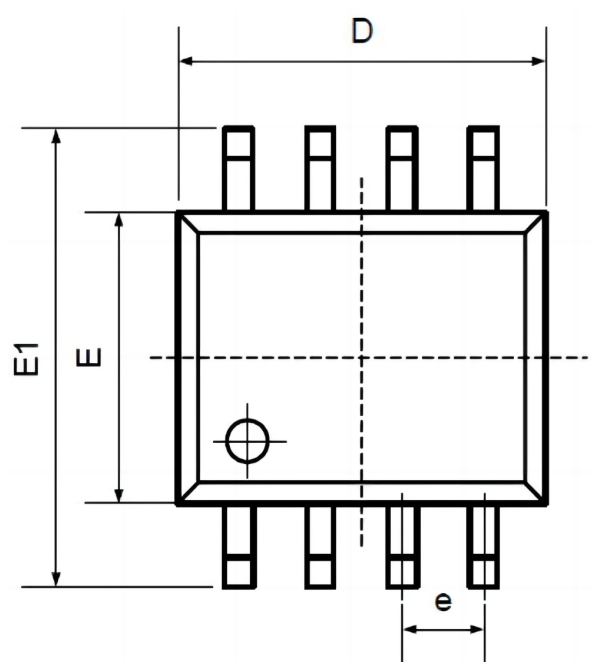




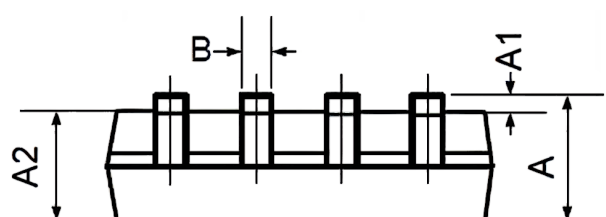
Order information

Order Number	Package	Package Quantity	Marking On The park
LD1117DT33CTR-TUDI	TO252	Tape,Reel,500	LD1117DT33CTR
LD1117DT33TR-TUDI	TO252	Tape,Reel,500	LD1117DT33TR
LD1117S33CTR-TUDI	SOT223	Tape,Reel,2500	LD1117S33CTR
LD1117S33TR-TUDI	SOT223	Tape,Reel,2500	LD1117S33TR

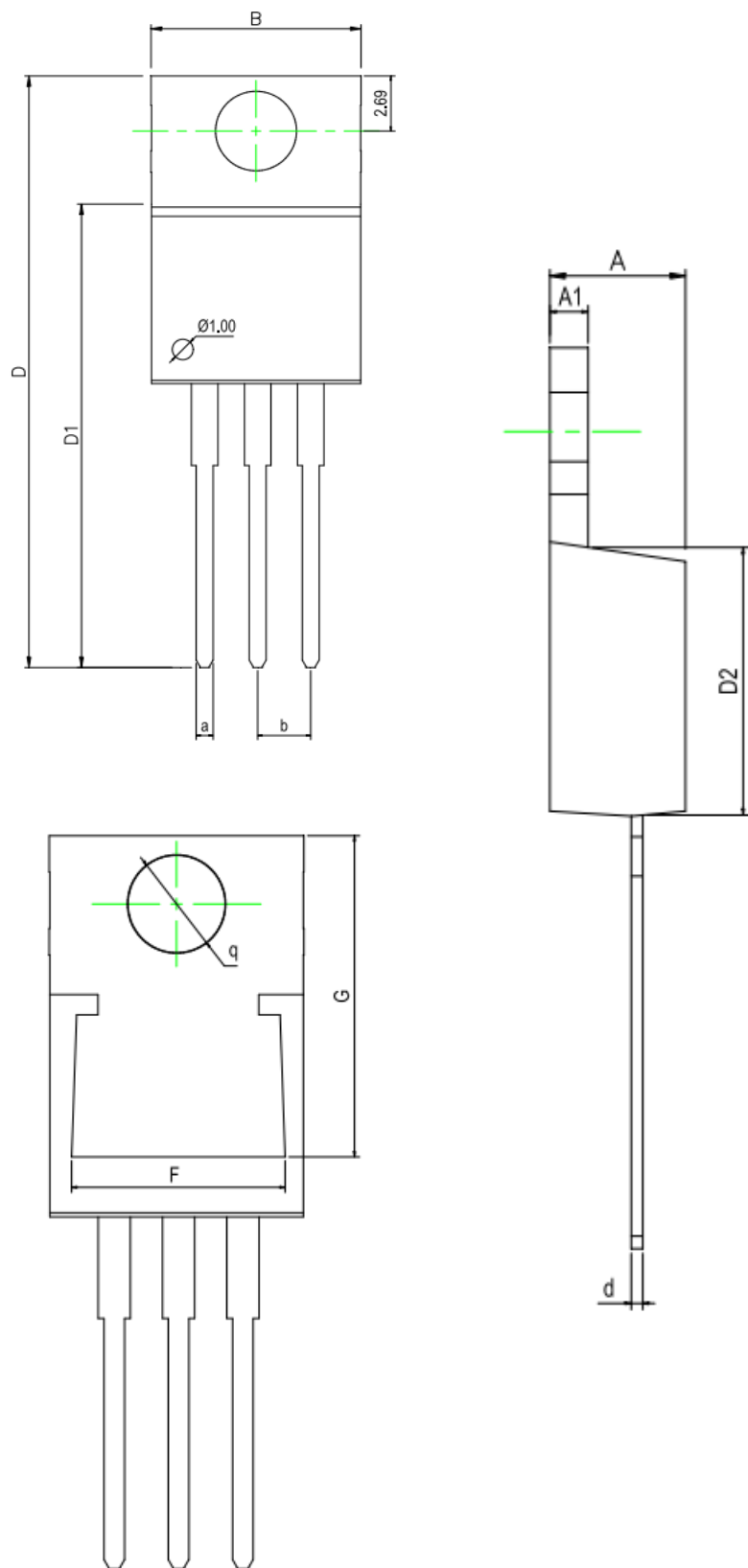
Package SOP8



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.350	1.750	0.053	0.069
A1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
B	0.330	0.510	0.013	0.020
C	0.190	0.250	0.007	0.010
D	4.780	5.000	0.188	0.197
E	3.800	4.000	0.150	0.157
E1	5.800	6.300	0.228	0.248
e	1.270TYP		0.050TYP	
L	0.400	1.270	0.016	0.050
θ	0°	8°	0°	8°



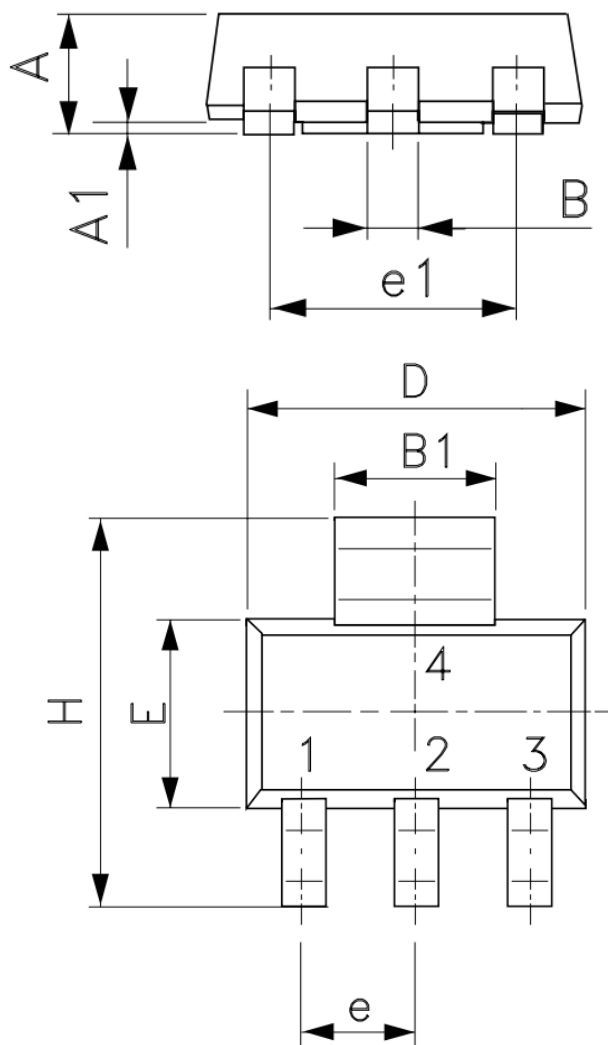
Package TO220-3



Symbol:	Min:	Max:
A	4.45	4.62
A1	1.22	1.32
B	10	10.4
D	28.2	28.9
D1	22.22	22.62
D2	8.5	9.1
F	8.3	8.55
G	12.55	12.75
a	0.71	0.97
d	0.33	0.42
b	2.54BSC	
q	3.8TYP	



Package SOT223



Dim.	mm		
	Min.	Typ.	Max.
A			1.80
A1	0.02		0.10
B	0.60	0.70	0.85
B1	2.90	3.00	3.15
C	0.24	0.26	0.35
D	6.30	6.50	6.70
e		2.30	
e1		4.60	
E	3.30	3.50	3.70
H	6.70	7.00	7.30
V			10 °

